

# Vishay General Semiconductor

# **Surface Mount TRANSZORB® Transient Voltage Suppressors**



DO-214AA (SMBJ)

PRIMARY CHARACTERISTICS				
$V_{WM}$	3.3 V			
$P_{PPM}$	600 W			
I <sub>FSM</sub>	60 A			
T <sub>J</sub> max.	175 °C			

### **FEATURES**

- Uni-directional polarity only
- Peak pulse power: 600 W (10/1000 μs)
- Excellent clamping capability
- Very fast response time
- Meets MSL level 1, per J-STD-020, LFRoHS maximum peak of 260 °C
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

### TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting on ICs, MOSFET, signal lines of sensor units specifically for protecting 3.3 V supplied sensitive equipment against transient overvoltages.

## **MECHANICAL DATA**

Case: DO-214AA (SMBJ)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS compliant, commercial grade Base P/NHE3 - RoHS compliant, high reliability/ automotive grade (AEC Q101 qualified)

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: Color band denotes cathode end

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	VALUE	UNIT			
Peak pulse power dissipation (1)(2)	P <sub>PPM</sub>	600	W			
Peak pulse current with a 10/1000 μs waveform (Fig. 1)	I <sub>PP</sub>	50	Α			
Peak pulse current with a 8/20 waveform (Fig. 1)	I <sub>PPM</sub>	200	Α			
Non repetitive peak forward surge current 8.3 ms single half sine-wave (2)	I <sub>FSM</sub>	60	Α			
Power dissipation on infinite heatsink, T <sub>L</sub> = 75 °C	P <sub>D</sub>	5	W			
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	- 65 to + 175	°C			

### Notes:

- (1) Non-repetitive current pulse, per Fig. 1
- (2) Mounted on 0.2 x 0.2" (5.0 x 5.0 mm) copper pads to each terminal

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)											
DEVICE TYPE	DEVICE MARKING CODE	_	AGE AT I <sub>T</sub>	MAXIMUM REVERSE LEAKAGE CURRENT I <sub>R</sub> AT V <sub>WM</sub> MAX.		CLAN VOLT V <sub>C</sub> A	$ \begin{array}{c cccc} \text{MAXIMUM} & \text{MAXIMUM} \\ \text{CLAMPING} & \text{CLAMPING} \\ \text{VOLTAGE} & \text{VOLTAGE} \\ \text{V}_{\text{C}} \text{ AT I}_{\text{PP}} & \text{V}_{\text{C}} \text{ AT I}_{\text{PPM}} \\ 10/1000  \mu \text{s} & 8/20  \mu \text{s} \end{array} $		IPING ΓAGE Γ Ι <sub>ΡΡΜ</sub>	TYPICAL TEMP. COEFFICIENT OF V <sub>BR</sub>	TYPICAL JUNCTION CAPACITANCE C <sub>J</sub> AT 0 V 1 MHz
		V	mA	μΑ	V	V	Α	V	Α	(10 <sup>-4</sup> /°C)	pF
SMBJ3V3	KC	4.1	1.0	200	3.3	7.3	50	10.3	200	- 5.3	5200

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THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	VALUE	UNIT		
Typical thermal resistance, junction to lead <sup>(1)</sup>	$R_{ hetaJL}$	20	°C/W		
Typical thermal resistance, junction to ambient (2)	$R_{ hetaJA}$	100	- °C/vv		

#### Notes:

- (1) Thermal resistance from junction to lead mounted on 0.2 x 0.2" (5.0 x 5.0 mm) copper pads to each terminal
- (2) Thermal resistance from junction to ambient mounted on the recommended P.C.B. pad layout

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
SMBJ3V3-E3/52	0.096	52	750	7" diameter plastic tape and reel		
SMBJ3V3-E3/5B	0.096	5B	3200	13" diameter plastic tape and reel		
SMBJ3V3HE3/52 <sup>(1)</sup>	0.096	52	750	7" diameter plastic tape and reel		
SMBJ3V3HE3/5B (1)	0.096	5B	3200	13" diameter plastic tape and reel		

### Note:

(1) Automotive grade AEC Q101 qualified

## **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

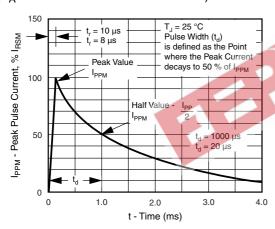


Figure 1. Pulse Waveform

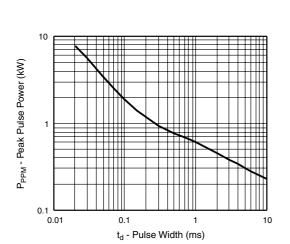


Figure 2. Peak Pulse Power Rating Curve

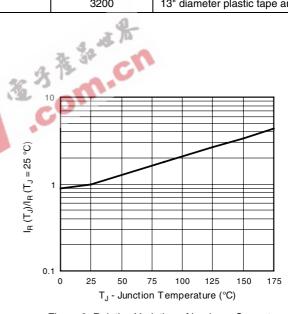


Figure 3. Relative Variation of Leakage Current vs. Junction Temperature

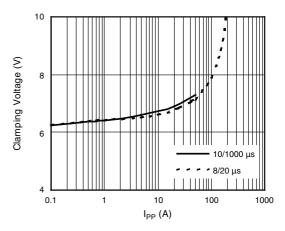


Figure 4. Clamping Voltage vs. Peak Pulse Current  $(T_J \text{ initial} = 25 \, ^{\circ}\text{C})$ 



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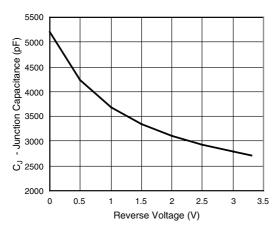


Figure 5. Typical Junction Capacitance

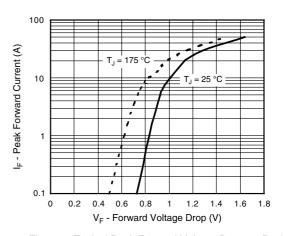


Figure 7. Typical Peak Forward Voltage Drop vs. Peak
Forward Current

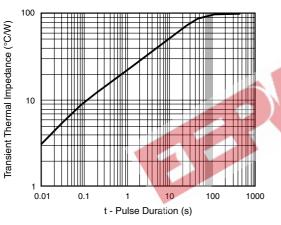
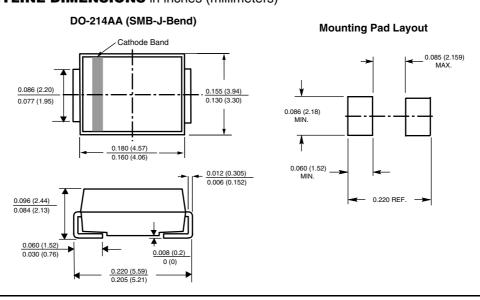


Figure 6. Typical Transient Thermal Impedance

# PACKAGE OUTLINE DIMENSIONS in inches (millimeters)







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Revision: 18-Jul-08

Document Number: 91000 www.vishay.com